

QUAD 2-INPUT MULTIPLEXER

The LSTTL/MSI SN54/74LS157 is a high speed Quad 2-Input Multiplexer. Four bits of data from two sources can be selected using the common Select and Enable inputs. The four buffered outputs present the selected data in the true (non-inverted) form. The LS157 can also be used to generate any four of the 16 different functions of two variables. The LS157 is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all Motorola TTL families.

- Schottky Process for High Speed
- Multifunction Capability
- Non-Inverting Outputs
- Input Clamp Diodes Limit High Speed Termination Effects
- Special Circuitry Ensures Glitch Free Multiplexing
- ESD > 3500 Volts



PIN NAMES		LOADING (Note a)		
		HIGH	LOW	
<u>S</u>	Common Select Input	1.0 U.L.	0.5 U.L.	
E	Enable (Active LOW) Input	1.0 U.L.	0.5 U.L.	
I _{0a} -I _{0d}	Data Inputs from Source 0	0.5 U.L.	0.25 U.L.	
I _{1a} -I _{1d}	Data Inputs from Source 1	0.5 U.L.	0.25 U.L.	
Za-Zd	Multiplexer Outputs (Note b)	10 U.L.	5 (2.5) U.L.	

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μA HIGH/1.6 mA LOW.

b) The Output LOW drive factor is 2.5 U.L. for Military (54) and 5 U.L. for Commercial (74) Temperature Ranges.

LOGIC DIAGRAM



QUAD 2-INPUT MULTIPLEXER LOW POWER SCHOTTKY							
	J SUFFIX CERAMIC CASE 620-09						
16 1	N SUFFIX PLASTIC CASE 648-08						
16 1886 1887 18	D SUFFIX SOIC CASE 751B-03						
ORDERING INI	FORMATION						
SN54LSXXXJ SN74LSXXXN SN74LSXXXD	Ceramic Plastic SOIC						

SN54/74LS157



FUNCTIONAL DESCRIPTION

The LS157 is a Quad 2-Input Multiplexer fabricated with the Schottky barrier diode process for high speed. It selects four bits of data from two sources under the control of a common Select Input (S). The Enable Input (E) is active LOW. When E is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs.

The LS157 is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select Input. The logic equations for the outputs are:

$$Z_{a} = \overline{E} \cdot (I_{1a} \cdot S + I_{0a} \cdot \overline{S}) \qquad Z_{b} = \overline{E} \cdot (I_{1b} \cdot S + I_{0b} \cdot \overline{S})$$
$$Z_{c} = \overline{E} \cdot (I_{1c} \cdot S + I_{0c} \cdot \overline{S}) \qquad Z_{d} = \overline{E} \cdot (I_{1d} \cdot S + I_{0d} \cdot \overline{S})$$

A common use of the LS157 is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select Input. A less obvious use is as a function generator. The LS157 can generate any four of the 16 different functions of two variables with one variable common. This is useful for implementing highly irregular logic.

ENABLE	SELECT INPUT	INPUTS		OUTPUT			
E	S	I ₀	I ₁	Z			
Н	Х	Х	Х	L			
L	Н	Х	L	L			
L	Н	Х	Н	Н			
L	L	L	Х	L			
L	L	н	Х	Н			

TRUTH TABLE

H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

GUARANTEED OPERATING RANGES

Symbol	Parameter		Min	Тур	Max	Unit
VCC	Supply Voltage	54 74	4.5 4.75	5.0 5.0	5.5 5.25	V
T _A	Operating Ambient Temperature Range	54 74	-55 0	25 25	125 70	°C
ЮН	Output Current — High	54, 74			-0.4	mA
IOL	Output Current — Low	54 74			4.0 8.0	mA

SN54/74LS157

				Limits					
Symbol	Parameter		Min	Тур	Max	Unit	Test Conditions		
VIH	Input HIGH Voltage		2.0			V	Guaranteed Input All Inputs	HIGH Voltage for	
		54			0.7	v	Guaranteed Input	LOW Voltage for	
VIL	Input LOW Voltage	74			0.8	v	All Inputs		
V _{IK}	Input Clamp Diode Voltage	Э		-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} = -18 \text{ mA}$		
Mari	Output HIGH Voltage	54	2.5	3.5		V	$V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH}$		
VOH	Output HIGH voltage	74	2.7	3.5		V	or VIL per Truth T		
Max		54, 74		0.25	0.4	V	I _{OL} = 4.0 mA	V _{CC} = V _{CC} MIN, V _{IN} = V _{IL} or V _{IH}	
VOL	L Output LOW Voltage	74		0.35	0.5	V	I _{OL} = 8.0 mA	per Truth Table	
Чн	Input HIGH Current Iq, I1 E, S				20 40	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V	
	<u>Ι</u> ο, Ι ₁ Ε, S				0.1 0.2	mA	V _{CC} = MAX, V _{IN}	= 7.0 V	
IIL	Input LOW Current L <u>I</u> ₀ , I ₁ E, S				-0.4 -0.8	mA	V _{CC} = MAX, V _{IN}	= 0.4 V	
IOS	Short Circuit Current (Note 1)		-20		-100	mA	V _{CC} = MAX		
ICC	Power Supply Current				16	mA	V _{CC} = MAX		

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25° C)

		Limits					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions	
^t PLH ^t PHL	Propagation Delay Data to Output		9.0 9.0	14 14	ns	Figure 2	
^t PLH ^t PHL	Propagation Delay Enable to Output		13 14	20 21	ns	Figure 1	V _{CC} = 5.0 V C _L = 15 pF
^t PLH ^t PHL	Propagation Delay Select to Output		15 18	23 27	ns	Figure 2	

AC WAVEFORMS







Figure 2

Case 751B-03 D Suffix **16-Pin Plastic** SO-16



Case 648-08 N Suffix **16-Pin Plastic**





- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER. DIMENSION A AND B DO NOT INCLUDE MOLD 2 3.
- PROTRUSION. MAXIMUM MOLD PROTRUSION 0.15 (0.006) 4.
- PER SIDE. 751B-01 IS OBSOLETE, NEW STANDARD 751B-03. 5.

	MILLIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
М	0°	7 °	0°	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2.
- CONTROLLING DIMENSION: INCH. DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL. 3.
- DIMENSION "B" DOES NOT INCLUDE MOLD 4. FLASH.
- 5.
- ROUNDED CORNERS OPTIONAL. 648-01 THRU -07 OBSOLETE, NEW STANDARD 6. 648-08.

	MILLIM	ETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	18.80	19.55	0.740	0.770	
В	6.35	6.85	0.250	0.270	
С	3.69	4.44	0.145	0.175	
D	0.39	0.53	0.015	0.021	
F	1.02	1.77	0.040	0.070	
G	2.54	BSC	0.100 BSC		
н	1.27	BSC	0.050 BSC		
J	0.21	0.38	0.008	0.015	
ĸ	2.80	3.30	0.110	0.130	
L	7.50	7.74	0.295	0.305	
М	0°	10°	0°	10°	
S	0.51	1.01	0.020	0.040	

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL 4. DIM F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY. 5. 620-01 THRU -08 OBSOLETE, NEW STANDARD 620-09.

- 620-09.

	MILLIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	19.05	19.55	0.750	0.770
В	6.10	7.36	0.240	0.290
С	_	4.19	-	0.165
D	0.39	0.53	0.015	0.021
E	1.27	1.27 BSC		BSC
F	1.40	1.77	0.055	0.070
G	2.54	BSC	0.100 BSC	
J	0.23	0.27	0.009	0.011
K	_	5.08	_	0.200
L	7.62	7.62 BSC		BSC
M	0°	15°	0°	15°
N	0.39	0.88	0.015	0.035

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